

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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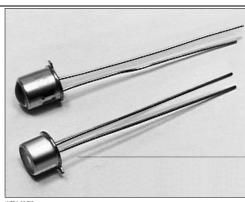
GaAs Infrared Emitting Diode

FEATURES

- TO-46 metal can package
- · Choice of flat window or lensed package
- 90° or 20° (nominal) beam angle option
- 935 nm wavelength
- Wide operating temperature range (-55°C to +125°C)
- Ideal for high pulsed current applications
- Mechanically and spectrally matched to SD3421/5421 photodiode, SD3443/5443/5491phototransistor, SD3410/5410 photodarlington and SD5600 series Schmitt trigger



The SE3455/5455 series consists of a gallium arsenide infrared emitting diode mounted in a TO-46 metal can package. The SE3455 series has flat window cans providing a wide beam angle, while the SE5455 series has glass lensed cans providing a narrow beam angle. These devices are constructed with dual bond wires suitable for pulsed current applications. The TO-46 packages offer high power dissipation capability and are ideally suited for operation in hostile environments.

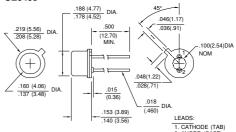


INFRA-83.TIF

OUTLINE DIMENSIONS in inches (mm)

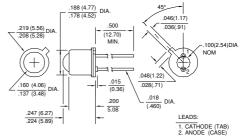
Tolerance 3 plc decimals $\pm 0.005(0.12)$ 2 plc decimals $\pm 0.020(0.51)$

SE3455



DIM_005a.ds4

SE5455



DIM_005b.ds4

Honeywell

Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

GaAs Infrared Emitting Diode

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Total Power Output	Po				mW	I _F =100 mA
SE3455-001, SE5455-001		2.0				
SE3455-002, SE5455-002		3.5				
SE3455-003, SE5455-003		4.8				
SE3455-004, SE5455-004		5.4				
Forward Voltage	VF			1.7	V	I _F =100 mA
Reverse Breakdown Voltage	V_{BR}	3.0			V	I _R =10 μA
Peak Output Wavelength	$\lambda_{ m p}$		935		nm	
Spectral Bandwidth	$\Delta \lambda$		50		nm	
Spectral Shift With Temperature	$\Delta \lambda_p / \Delta_T$		0.3		nm/°C	
Beam Angle (1)	Ø				degr.	I _F =Constant
SE3455			90			
SE5455			20			
Radiation Rise And Fall Time	t _r , t _f		0.7		μs	

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted) Continuous Forward Current 100 mA **Peak Forward Current** 3 A

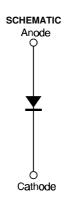
(1µs pulse width, 300 pps)

150 mW (1) Power Dissipation Operating Temperature Range -55°C to 125°C Storage Temperature Range -65°C to 150°C 260°C

Soldering Temperature (10 sec)

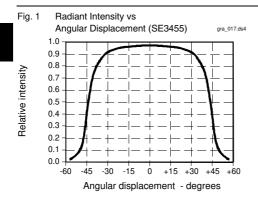
1. Derate linearly from 25°C free-air temperature at the rate of

1.43 mW/°C.

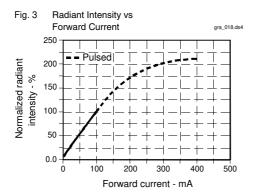


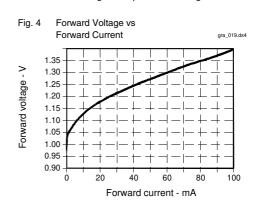
Notes
1. Beam angle is defined as the total included angle between the half intensity points.

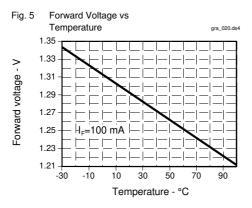
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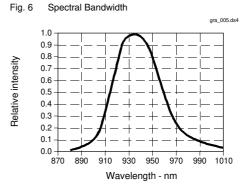


Radiant Intensity vs Angular Displacement (SE5455) gra_023.ds4 1.0 0.9 Relative intensity 0.7 0.6 0.5 0.4 0.2 0.1 0.0 -40 -20 -10 Ó +10 +20 +30 Angular displacement - degrees

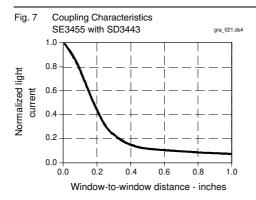


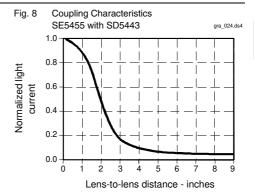


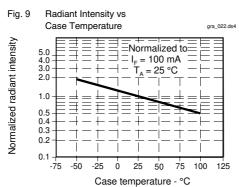




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All Performance Curves Show Typical Values